

#### Description

The 74LVCE1G86 is a single 2-input positive EXCLUSIVE OR gate with a standard totem pole output. The device is designed for operation with a power supply range of 1.4V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output preventing damaging current backflow when the device is powered down.

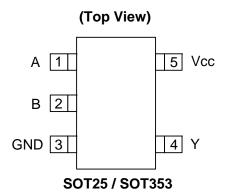
The gate performs the positive Boolean function:

$$Y = A \oplus B$$
 or  $Y = \overline{A}B + A\overline{B}$ 

#### **Features**

- Extended Supply Voltage Range from 1.4 to 5.5V
- Switching speed characterized for operation at 1.5V
- Offers 30% speed improvement over LVC at 1.8V.
- ± 24mA Output Drive at 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs accept up to 5.5V
- ESD Protection Exceeds JESD 22
- 200-V Machine Model (A115-A)
- 2000-V Human Body Model (A114-A)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- Range of Package Options
- · Direct Interface with TTL Levels
- SOT25 and SOT353: Assembled with "Green" Molding Compound (No Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

#### **Pin Assignments**



### **Applications**

- Voltage Level Shifting
- · Bus Driver / Repeater
- Parity Bit Generation
- Selectable signal Inverter
- Power Down Signal Isolation
- General Purpose Logic
- Wide array of products such as.
  - PCs, networking, notebooks, netbooks, PDAs
  - · Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
  - · Cell Phones, Personal Navigation / GPS
  - MP3 players ,Cameras, Video Recorders

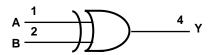
Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead\_free.html.



## **Pin Descriptions**

Pin Name	Pin NO.	Description			
А	1	Data Input			
В	2	Data Input			
GND	3	Ground			
Υ	4	Data Output			
Vcc	5	Supply Voltage			

# **Logic Diagram**



## **Function Table**

Inp	Output	
Α	В	Y
Η	Η	L
L	Η	H
Н	L	Н
Ĺ	L	L



## **Absolute Maximum Ratings (Note 2)**

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>cc</sub>	Supply Voltage Range	-0.5 to 6.5	V
Vı	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high impedance or I <sub>OFF</sub> state	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.3 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> <0	-50	mA
I <sub>OK</sub>	Output Clamp Current	-50	mA
Io	Continuous output current	±50	mA
	Continuous current through Vdd or GND	±100	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to 150	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



# **Recommended Operating Conditions (Note 3)**

Symbol		Parameter	Min	Max	Unit	
\/	On a ratio a Valta as	Operating	1.4	5.5	V	
$V_{CC}$	Operating Voltage	Data retention only	1.2		V	
		V <sub>CC</sub> = 1.4 V to 1.95 V	0.65 X V <sub>CC</sub>			
\/	High lovel langet Voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
$V_{IH}$	High-level Input Voltage	V <sub>CC</sub> = 3 V to 3.6 V	2		V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.7 X V <sub>CC</sub>			
		V <sub>CC</sub> = 1.4 V to 1.95 V		0.35 X V <sub>CC</sub>		
\/	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 3 V to 3.6 V		0.8	V	
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.3 X V <sub>CC</sub>		
Vı	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V <sub>cc</sub>	V	
		Vcc=1.4 V		-3		
	High lovel output ourrent	V <sub>CC</sub> = 1.65 V		-4	mA	
		V <sub>CC</sub> = 2.3 V		-8		
I <sub>OH</sub>	High-level output current	V 2V		-16	MA	
		$V_{CC} = 3 V$		-24	1	
		V <sub>CC</sub> = 4.5 V		-32		
		Vcc=1.4 V		3		
		V <sub>CC</sub> = 1.65 V		4		
	l avvilaval avtavt avenant	V <sub>CC</sub> = 2.3 V		8	mA	
I <sub>OL</sub>	Low-level output current	V 2V		16		
		$V_{CC} = 3 V$		24		
		V <sub>CC</sub> = 4.5 V		32		
		$V_{CC} = 1.4 \text{ to } 3V$		20		
Δt/ΔV	Input transition rise or fall	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
	rate	$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		5		
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

Notes: 3. Unused inputs should be held at Vcc or Ground.



## Electrical Characteristics (All typical values are at Vcc = 3.3V, T<sub>A</sub> = 25°C)

Over recommended free-air temperature range (unless otherwise noted)

		Vcc	Min	Тур.	Max	Unit
	$I_{OH} = -100 \mu A$	1.4 V to 5.5V	V <sub>CC</sub> - 0.1			
	$I_{OH} = -3mA$	1.4 V	1.05			
	$I_{OH} = -4mA$	1.65 V	1.2			
	$I_{OH} = -8mA$	2.3V	1.9			V
Voltage	$I_{OH} = -16mA$	2 \/	2.4			
	$I_{OH} = -24mA$	] 3 V	2.3			
	$I_{OH} = -32mA$	4.5 V	3.8			
	$I_{OL} = 100 \mu A$	1.4 V to 5.5V			0.1	
	$I_{OL} = 3mA$	1.4V			.4	
	$I_{OL} = 4mA$	1.65 V			0.45	V
High-level Input Voltage	$I_{OL} = 8mA$	2.3V			0.3	
	I <sub>OL</sub> = 16mA	2 \/			0.4	
	$I_{OL} = 24mA$	]			0.55	
	$I_{OL} = 32mA$	4.5			0.55	
Input Current	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			± 5	μΑ
Power Down Leakage Current	$V_1$ or $V_0 = 5.5V$	0			± 10	μA
Supply Current	$V_1 = 5.5V$ of GND $I_0=0$	1.4 V to 5.5V			10	μΑ
Additional Supply Current	One input at V <sub>CC</sub> – 0.6 V Other inputs at V <sub>CC o</sub> r GND	3 V to 5.5V			500	μA
Input Capacitance	$V_i = V_{CC} - \text{ or GND}$	3.3		3.5		pF
Thermal Resistance	SOT25	(Note 4)		204		°C/W
Junction-to-Ambient	SOT353	(Note 4)		371		°C/W
Thermal Resistance	SOT25	(Note 4)		52		°C/W
Junction-to-Case	SOT353	(Note 4)		143		°C/W
	Input Current Power Down Leakage Current Supply Current Additional Supply Current Input Capacitance Thermal Resistance Junction-to-Ambient Thermal Resistance	$\begin{tabular}{ll} High Level Output Voltage & $I_{OH} = -4mA$ \\ $I_{OH} = -8mA$ \\ $I_{OH} = -16mA$ \\ $I_{OH} = -24mA$ \\ $I_{OH} = -32mA$ \\ \hline $I_{OL} = 100\mu A$ \\ $I_{OL} = 3mA$ \\ \hline $I_{OL} = 4mA$ \\ \hline $I_{OL} = 4mA$ \\ \hline $I_{OL} = 4mA$ \\ \hline $I_{OL} = 16mA$ \\ \hline $I_{OL} = 16mA$ \\ \hline $I_{OL} = 24mA$ \\ \hline $I_{OL} = 32mA$ \\ \hline $I_{OL} = 32mA$ \\ \hline $I_{DL} = 32mA$ \\ \hline $I_{DL} = 32mA$ \\ \hline $I_{OL} = 32mA$ \\ \hline $I_{O$	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	High Level Output Voltage    I <sub>OH</sub> = -4mA	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

Notes: 4. Test condition for SOT25 and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



## **Switching Characteristics**

Over recommended free-air temperature range, CL = 15pF (see Figure 1)

Parameter	From	то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V ).2V		: 3.3 V ).3V		= 5 V ).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
$t_{pd}$	A or B	Y	2.1	9.1	1.4	6.3	0.8	3.6	0.6	3.2	0.7	2.9	ns

Over recommended free-air temperature range, CL = 30 or 50pF as noted (see Figure 2)

Parameter	From	то	Vcc = ± 0			: 1.8 V .15V		: 2.5 V ).2V		: 3.3 V ).3V		= 5 V ).5V	Unit
	(Input)	(OUTPUT)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t <sub>pd</sub>	A or B	Y	3.5	9.9	2.4	6.9	1.4	4.4	1	4.1	0.9	3.6	ns

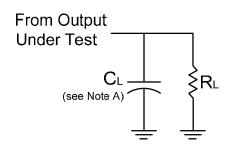
## **Operating Characteristics**

 $T_A = 25$  °C

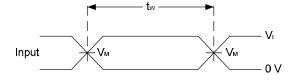
P	arameter	Test Conditions	Vcc = 1.5 V TYP	Vcc = 1.8 V	Vcc = 2.5 V TYP	Vcc = 3.3 V	Vcc = 5 V TYP	Unit
$C_{\sf pd}$	Power dissipation capacitance	f = 10 MHz	22	22	22	22	24	pF



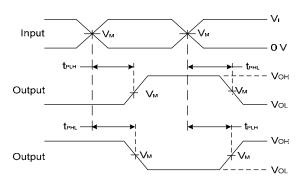
#### **Parameter Measurement Information**



Vcc	Inj	outs	V	<b>C</b> .	D.
VCC	Vı	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL	RL
1.5V±0.1V	V <sub>cc</sub>	≤2ns	V <sub>CC</sub> /2	15pF	1ΜΩ
1.8V±0.15V	V <sub>cc</sub>	≤2ns	V <sub>CC</sub> /2	15pF	1ΜΩ
2.5V±0.2V	$V_{CC}$	≤2ns	V <sub>CC</sub> /2	15pF	1ΜΩ
3.3V±0.3V	3V	≤2.5ns	1.5V	15pF	1ΜΩ
5V±0.5V	V <sub>cc</sub>	≤2.5ns	V <sub>CC</sub> /2	15pF	1ΜΩ



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

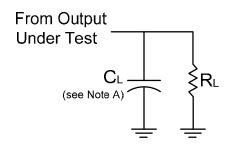
C. Inputs are measured separately one transition per measurement.

D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD.}$ 

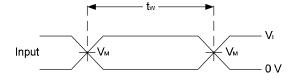
Figure 1. Load Circuit and Voltage Waveforms



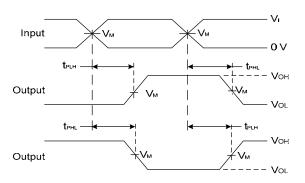
### **Parameter Measurement Information (Continued)**



Vcc	Inp	outs	V <sub>M</sub>	CL	$R_L$
	VI	t <sub>r</sub> /t <sub>f</sub>	- 101	o <sub>L</sub>	
1.5V±0.15	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30pF	1ΚΩ
1.8V±0.15V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30pF	1ΚΩ
2.5V±0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	30pF	500Ω
3.3V±0.3V	3V	≤2.5ns	1.5V	50pF	500Ω
5V±0.5V	V <sub>CC</sub>	≤2.5ns	V <sub>CC</sub> /2	50pF	500Ω



Voltage Waveform Pulse Duration



Voltage Waveform
Propagation Delay Times
Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.

C. Inputs are measured separately one transition per measurement.

D.  $t_{\mbox{\scriptsize PLH}}$  and  $t_{\mbox{\scriptsize PHL}}$  are the same as  $t_{\mbox{\scriptsize PD.}}$ 

Figure 2. Load Circuit and Voltage Waveforms



## **Ordering Information**

 74LVCE1G 86 XX - 7

 Logic Device
 Function
 Package
 Packing

 74 : Logic Prefix
 86 : 2-Input
 W5 : SOT25
 7 : Tape & Reel

 LVCE : 1.4 to 5.5V
 XOR-Gate
 SE : SOT353

 Family
 1G : One gate

Device	Package Packaging		7" Tape and Reel				
Device	Code	(Note 5)	Quantity	Part Number Suffix			
№ 74LVCE1G86W5-7	W6	SOT25	3000/Tape & Reel	-7			
№ 74LVCE1G86SE-7	SE	SOT353	3000/Tape & Reel	-7			

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

## **Marking Information**

## (Top View)

5 4 xx y w x

XX : Identification code

Y : Year 0~9

 $\underline{W}$ : Week : A $^{\sim}$ Z : 1 $^{\sim}$ 26 week;

a~z: 27~52 week; z represents

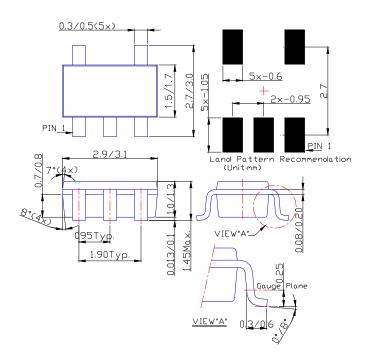
52 and 53 week  $\underline{X}$ :  $A^{\sim}Z$ : Internal code

Part Number	Package	Identification Code
74LVCE1G86W5	SOT25	PX
74LVCE1G86SE	SOT353	PX

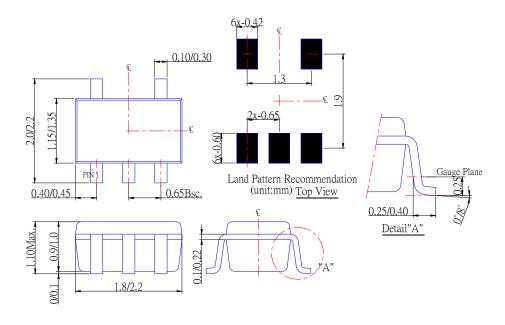


## Package Outline Dimensions (All Dimensions in mm)

### (1) Package Type: SOT25



#### (2) Package Type: SOT353





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